MT613X

Omni-polar, Low Power, 360 Degree Switch IC

1 Product Description

The MT613X family is produced with monolithic technology which builds AMR sensor & ASIC on one chip. The IC internally includes a Wheatstone bridge with magnetic film, a current regulator for operating with supply voltage from 1.65V to 5.0V, a sleep/awake logic for low power consumption requirement, small signal amplifier and Schmitt trigger comparator with dynamic offset cancellation, and an output driver with push pull output.

When combined with a magnet, it becomes a non-contact switch with low power consumption, high sensitivity and high reliability. All directions of horizontal magnetic field parallel to the electrode of the package can be detected by an arbitrary polarity.

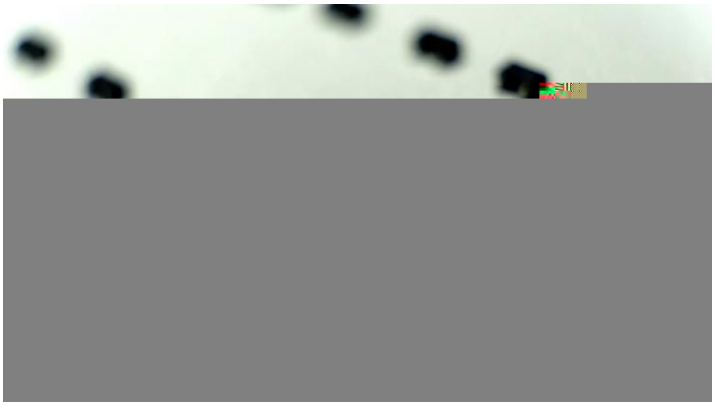
The MT613X family provide SOT-23 for surface mount RoHS compliant.

2 Feature

Monolithic Technology
360 Degree AMR (Anisotropic Magneto Resistance)
Omni-polar Switch
1.65 5.0V Operating Vcc Range
-40 ~125 Operating Temperature
Package Option:
SOT-23
Magnetic Sensitivity Option:
B_{OP}=±18Gs, B_{RP}=±13Gs
Push Pull & Open Drain Output Option:
MT6131 & MT6132: Push Pull
MT6133 & MT6135: Open Drain
Operation Frequency Option:
MT6131 & MT6133: 20Hz
MT6132 & MT6135: 1KHz
Low Power Consumption
RoHS Compliant: 2011/65/EU

3 Product Overview of MT613X

Part No.	Description
MT613XAT	SOT-23, tape & reel (3000pcs/bag)



4 Application

Home appliances, Industrial
Position Detection
Proximity Switch
Smart Meter
Speed Detection
Handheld Device
Consumer Device

5. Pin Configuration and Functions

	Vcc	Out	GND
SOT-23	1	2	3
Description	Power	Output Push Pull or Open Drain	Ground

SOT-23
Top-View

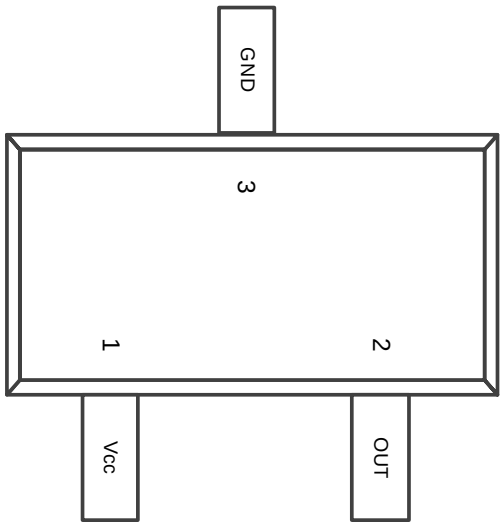


Figure.1 Pin Configuration & Functions

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Reversion History

1	Originally Version	2018 Nov

6 Definition of Switching Function

Figure.2 shows the device functionality and hysteresis

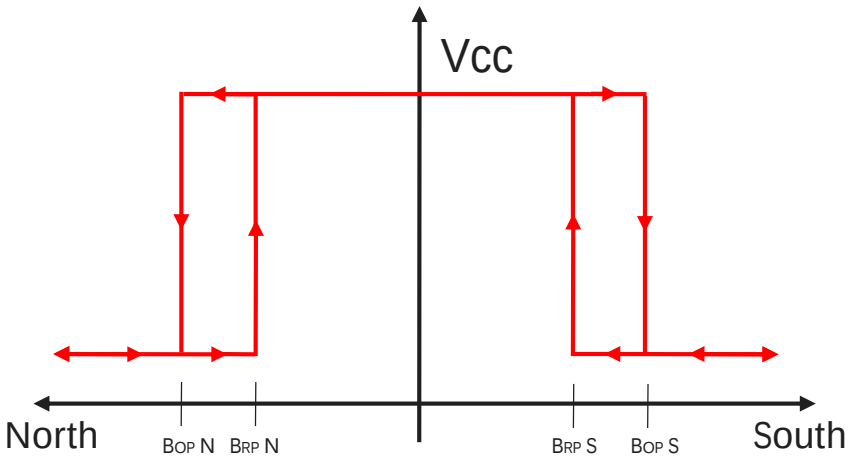


Figure.2 Omni-polar Switching Function

7 Function Description

B_{OP}: Operating Point, Magnetic flux density applied on the branded side of the package which turns the output driver ON (V_{OUT}=Low)

B_{RP}: Releasing Point, Magnetic flux density applied on the branded side of the package which turns the output driver OFF (V_{OUT}=High)

B_{HYST}: Hysteresis Window, $|B_{OP} - B_{RP}|$

8 Feature Description

The MT613X series is sensitive to the magnetic field that is parallel to the package (X & Y axis). To operate the MR switch, the magnetic field should be applied to the sensor parallel to the package. MT613X series detect the magnetic field in any parallel direction, but it does not respond to magnetic field in the vertical direction.

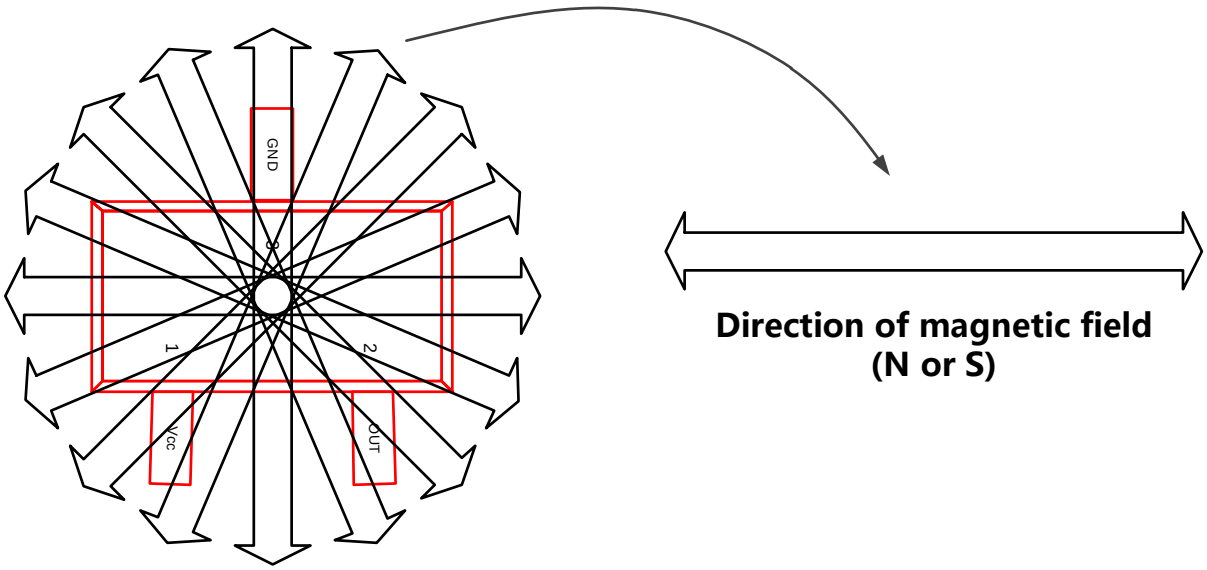


Figure.3 Detection of magnetic field

9 Functional Block Diagram

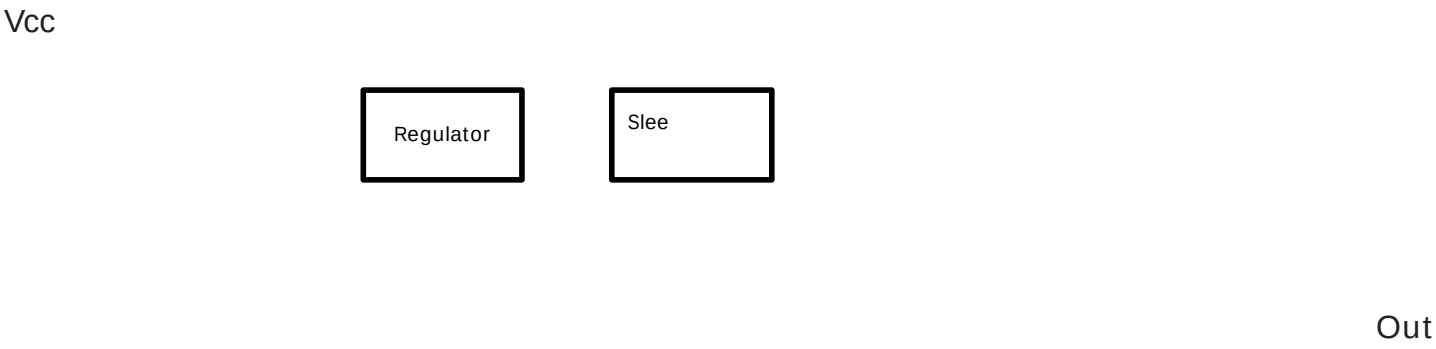


Figure.4 Functional Block Diagram (MT6131 & MT6132)

10 Electrical and Magnetic Characteristics

10.1 Absolute Maximum Ratings

Absolute maximum ratings are limited values to be applied individually, and beyond which the serviceability of the circuit may be impaired. Functional operability is not necessarily implied. Exposure to absolute maximum rating conditions for an extended period of time may affect device reliability.

Symbol	Parameters	Min	Max	Units
V_{CC}	Supply Voltage	-	7	V
V_{RCC}	Reverse Battery Voltage	-0.4	-	V
V_{OUT}	Output Voltage	-	7	V
I_{OUT}	Continuous Output Current	-	20	mA
T_A	Operating Ambient Temperature	-40	125	
T_S	Storage Temperature	-50	150	
T_J	Junction Temperature	-	165	
B	Magnetic Flux Density	1200		Gs

10.2 Electrical Specifications

At T_A=-40~125 , V_{CC}=1.65V~5.0V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	Operating	1.65	3.60	5.00	V
I_{CC}	Supply Current	MT6131 & MT6133, V_{CC}=3.6V, B < B_{RP}	1.0	2.0	3.0	uA
		MT6132 & MT6135, V_{CC}=3.6V, B < B_{RP}	10.0	15.0	20.0	uA
V_{OH}	Output High Voltage	MT6131 & MT6132, V_{CC}=5V, I_{OUT}=5mA, B > B_{OP}	4.6	-	-	V
V_{OL}	Output Low Voltage	V_{CC}=5V, I_{OUT}=-5mA, B > B_{OP}	-	-	0.4	V
I_{OFF}	Output Leakage Current	V_{OUT}=5V, B < B_{RP}	-	-	0.1	uA
T_{PO}	Power on Time	dV_{CC}/dt>3.6V/us, B>B_{OP}(MAX)	-	80	120	us
F_{OP}	Operation Frequency	MT6131 & MT6133, V_{CC}=3.6V	10	20	-	Hz
		MT6132 & MT6135, V_{CC}=3.6V	0.5K	1K	-	Hz
T_{AW}	Awake Time	V_{CC}=3.6V	-	16	-	us
T_{SL}	Sleep Time	V_{CC}=3.6V	-	50	-	ms
D.C.	Duty Cycle	V_{CC}=3.6V	-	0.03	-	%
R_{TH}	Thermal Resistance of SOT-23		-	301	-	/W

10.5 Characteristic Performance

Figure.6 Supply Current vs. Temperature

Figure.7 Magnetic Characteristics vs. Temperature
(BOP & BRP) (At VCC=3.6V)
Magnetic Field @ 90 Degree & 180 Degree

10.5 Characteristic Performance (continued)

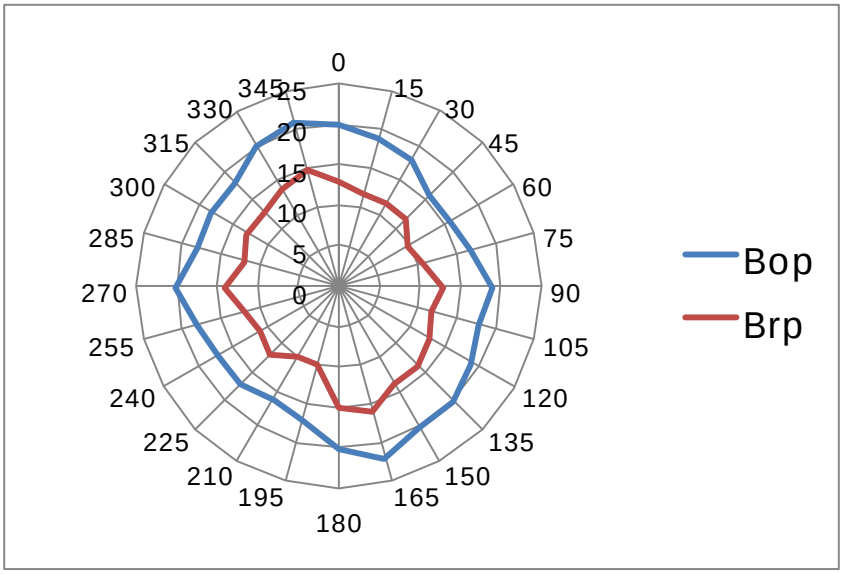
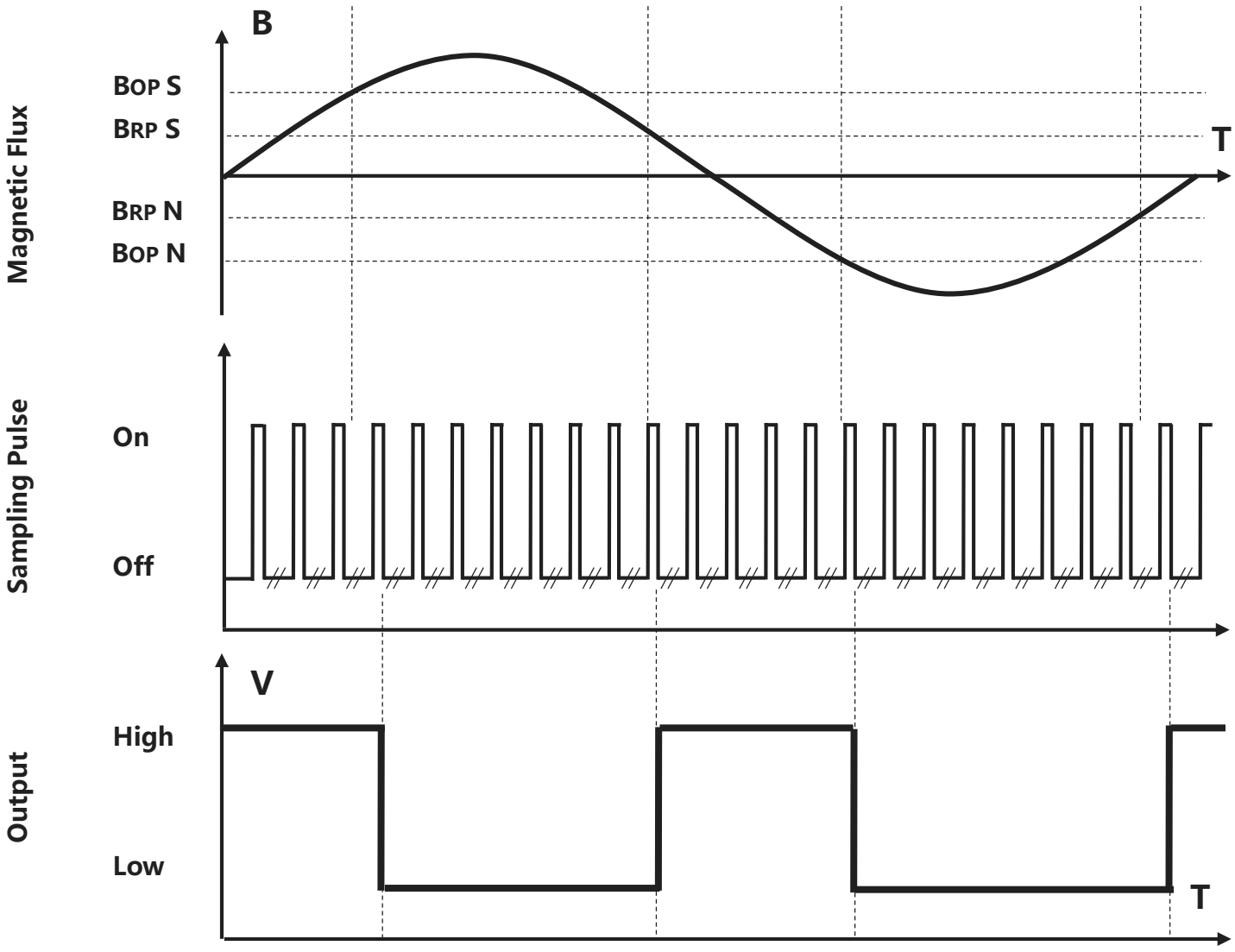


Figure.9 360 Degree Magnetic Characteristics (At V_{CC}=3.6V, T_A=25

10.6 Typical Output Waveform

MT6131A as example



Note: Output is not immediately updated until the chip wakes up from sleep mode and samples the input

Figure.10 Digital Output vs. Magnetic Flux Density & Sampling Pulse

11 Typical Application Circuit

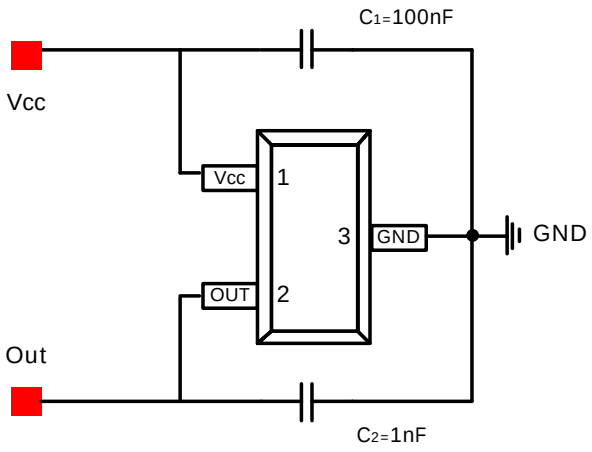


Figure.11 Typical Application Circuit
Push Pull Output
MT6131 & MT 6132

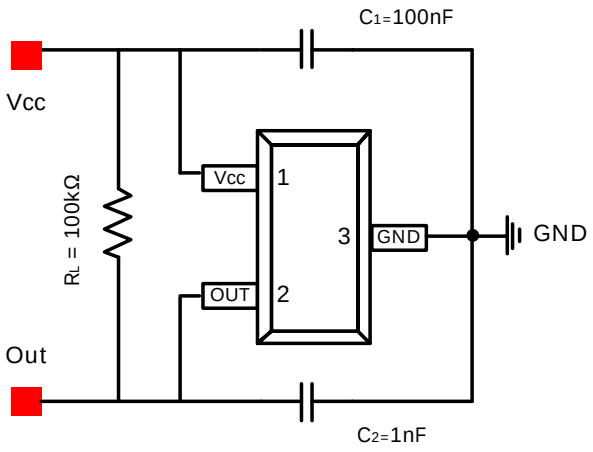


Figure.12 Typical Application Circuit
Open Drain Output
MT6133 & MT 6135

12 Power on Output Waveform

VCC rise time < 1us, TPO is the time from the stable point of VCC to the valid point of output

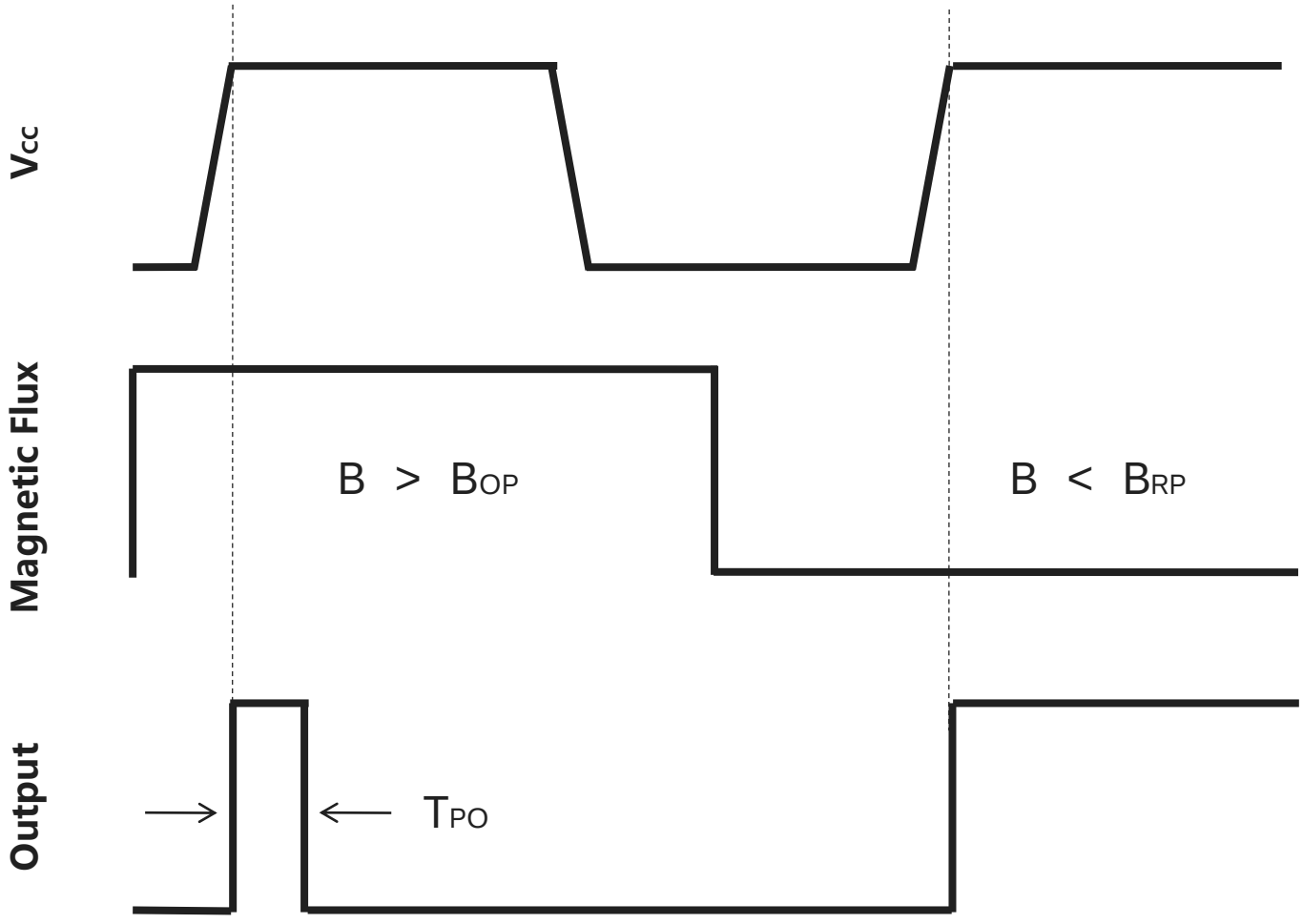


Figure.13 Power on Output Waveform

13 Package Material Information (For Reference Only – Not for Tooling Use)

13.1 SOT-23 Package Information